

DIOTEC ELECTRONICS CORP.

18020 Hobart Blvd., Unit B Gardena, CA 90248 U.S.A

Tel.: (310) 767-1052 Fax: (310) 767-7958

1 AMP GENERAL PURPOSE SILICON DIODES

FEATURES

MECHANICAL SPECIFICATION

ACTUAL SIZE OF DO-41 PACKAGE

SERIES 1N4001 - 1N4007

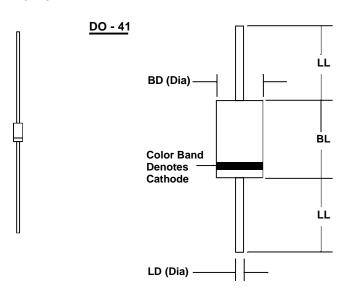
Low cost

- Low leakage
- Low forward voltage drop
- High current capacity
- Easily cleaned with freon, alcohol, chlorothene and similar solvents

MECHANICAL DATA

- Case: JEDEC DO-41, molded plastic (U/L Flammability Rating 94V-0)
- Terminals: Plated axial leads
- Soldering: Per MIL-STD 202 Method 208 guaranteed
- Polarity: Color band denotes cathode
- Mounting Position: Any

• Weight: 0.012 Ounces (0.34 Grams)



Sym	Mini	mum	Maximum				
Sylli	ln	mm	ln	mm			
BL	0.160	4.1	0.205	5.2			
BD	0.103	2.6	0.107	2.7			
LL	1.00	25.4					
LD	0.028	0.71	0.034	0.86			

MAXIMUM RATINGS & ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60Hz, resistive or inductive load. For capacitive loads, derate current by 20%.

PARAMETER (TEST CONDITIONS)	SYMBOL	RATINGS							UNITS	
Series Number		1N4001	1N4002	1N4003	1N4004	1N4005	1N4006	1N4007		
Maximum DC Blocking Voltage	VRM	50	100	200	400	600	800	1000		
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	VOLTS	
Maximum Peak Recurrent Reverse Voltage	VRRM	50	100	200	400	600	800	1000	1	
Average Forward Rectified Current @ TA = 75 °C (Lead length = 0.375 in. (9.5 mm))	lo	1						AMPS		
Peak Forward Surge Current (8.3 mSec single half sine wave superimposed on rated load)	IFSM	50								
Maximum Forward Voltage at 1 Amp DC	VFM	1						VOLTS		
Maximum Full Cycle Reverse Current @ T _L = 75 °C (Note 1)	IRM(AV)	30						μ Α		
Maximum Average DC Reverse Current @ TA = 25°C At Rated DC Blocking Voltage @ TA = 100°C	İRM	5 50								
Typical Thermal Resistance, Junction to Ambient (Note 1)		30						°C/W		
Typical Junction Capacitance (Note 2)		26						pF		
Operating and Storage Temperature Range		-65 to +175						°C		

NOTES: (1) Lead length = 0.375 in. (9.5 mm) (2) Measured at 1MHz & applied reverse voltage of 4 volts

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RATING & CHARACTERISTIC CURVES FOR SERIES 1N4001 - 1N4007

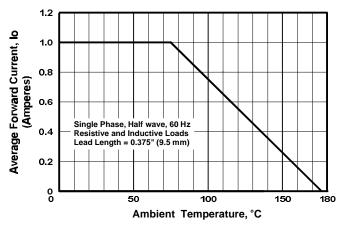


FIGURE 1. FORWARD CURRENT DERATING CURVE

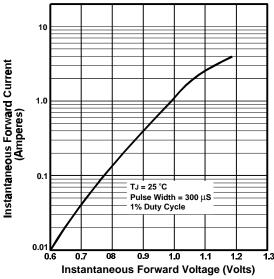


FIGURE 3. TYPICAL FORWARD CHARACTERISTIC PER DIODE

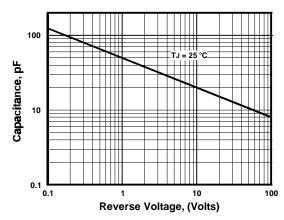


FIGURE 5. TYPICAL JUNCTION CAPACITANCE PER DIODE

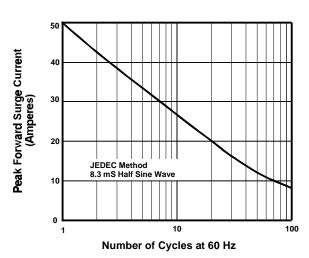


FIGURE 2. MAXIMUM NON-REPETITIVE SURGE CURRENT

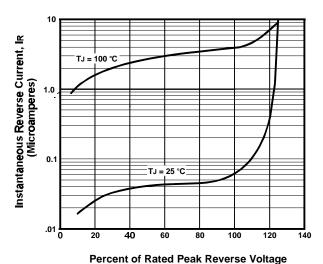


FIGURE 4. TYPICAL REVERSE CHARACTERISTICS

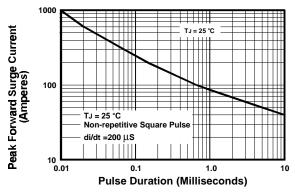


FIGURE 6. PEAK FORWARD SURGE CURRENT

H2